IBM Docket No.: FIS920030397US1

## **Declaration and Power of Attorney for Patent Application**

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name; I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled: A MANUFACTURABLE METHOD AND STRUCTURE FOR DOUBLE SPACER CMOS WITH OPTIMIZED NFET/PFET PERFORMANCE

the specification of which (ch	eck one)						
X is attach	ed hereto.						
was filed	l on	as Application Serial No.	and was amended on	<u></u> .			
I hereby state that I have revie by any amendment referred		e contents of the above-identified	specification, including the claims, as amend	led			
I acknowledge the duty to discof Federal Regulations, §1.5		is material to the patentability of ti	nis application in accordance with Title 37, Co	xde			
I hereby claim foreign priority certificate listed below and ha that of the application on whi	ve also identified below	5, United States Code, §119 of an any foreign application for patent o	ny foreign application(s) for patent or inventor r inventor's certificate having a filing date before	ore			
Prior Foreign Appli	Prior Foreign Application(s):						
Number	Country	Day/Month/Ye	ar Priority Claimed				
subject matter of each of the the first paragraph of Title 35	claims of this applicatio , United States Code, § I in Title 37, Code of F or PCT international filin	n is not disclosed in the prior Unito 112, I acknowledge the duty to d Federal Regulations, §1.56 which	es application(s) listed below and, insofar as to states application in the manner provided isclose information material to the patentable occurred between the filing date of the present	by ility			
Serial No.		Filing Date	Status				
are believed to be true; and f made are punishable by fine	urther that these staten or imprisonment, or bot	nents were made with the knowle	it all statements made on information and bel dge that wiliful false statements and the like of the United States Code and that such will ereon.	80			
As a named inventor, I here application and transact all be	by appoint the following usiness in the Patent are	g attorneys and/or agents listed nd Trademark Office connected th	under Customer No. 29154 to prosecute the terewith.	his			
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